NSN 5961-01-287-5654

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-287-5654 **Inclosure Material:** Glass **Overall Length:** 0.175 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.075 inches **Function For Which Designed:** Voltage variable capacitor Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 reverse voltage, dc **Voltage Tolerance In Percent:** -10.0/+10.0 **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 30.5 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No